PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

Rev. 07 — 20 April 2007

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET) family in small plastic packages.

Table 1. Product overview

| Type number | Package | NPN complement | | |
|--------------------------|---------|----------------|----------|-----------|
| | NXP | JEITA | JEDEC | |
| PDTA114TE | SOT416 | SC-75 | - | PDTC114TE |
| PDTA114TK | SOT346 | SC-59A | TO-236 | PDTC114TK |
| PDTA114TM | SOT883 | SC-101 | - | PDTC114TM |
| PDTA114TS ^[1] | SOT54 | SC-43A | TO-92 | PDTC114TS |
| PDTA114TT | SOT23 | - | TO-236AB | PDTC114TT |
| PDTA114TU | SOT323 | SC-70 | - | PDTC114TU |

[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Digital applications
- Control of IC inputs

1.4 Quick reference data

- Reduces component count
- Reduces pick and place costs
- Cost-saving alternative to BC857 series in digital applications
- Low current peripheral driver

Table 2. **Quick reference data** Symbol Conditions Parameter Min Max Unit Тур -50 collector-emitter voltage open base V VCEO -output current -100 mΑ I_{O} --R1 bias resistor 1 (input) 7 10 13 kΩ



PNP resistor-equipped transistors; R1 = 10 kΩ, R2 = open

2. Pinning information

| Pin | Description | Simplified outline | Symbol |
|----------|------------------------|---------------------------|--|
| SOT54 | | | |
| 1 | input (base) | | |
| 2 | output (collector) | | |
| 3 | GND (emitter) | | 1 R1 |
| SOT54A | | | |
| 1 | input (base) | | |
| 2 | output (collector) | | |
| 3 | GND (emitter) | 001aab348 | 1 R1 006aaa217 |
| SOT54 va | ariant | | |
| 1 | input (base) | | |
| 2 | output (collector) | | |
| 3 | GND (emitter) | 001aab447 | 1 R1 006aaa217 |
| SOT23; S | SOT323; SOT346; SOT416 | | |
| 1 | input (base) | | |
| 2 | GND (emitter) | 3 | |
| 3 | output (collector) | 1 2 006aaa144 | 1 - R1 - |
| SOT883 | | | |
| 1 | input (base) | | |
| 2 | GND (emitter) | | |
| 3 | output (collector) | 2 Transparent top view | |

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

3. Ordering information

| informatio | n | | | | |
|------------|---|---|--|--|--|
| Package | | | | | |
| Name | Description | Version | | | |
| SC-75 | plastic surface-mounted package; 3 leads | SOT416 | | | |
| SC-59A | plastic surface-mounted package; 3 leads | SOT346 | | | |
| SC-101 | leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5 \text{ mm}$ | SOT883 | | | |
| SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 | | | |
| - | plastic surface-mounted package; 3 leads | SOT23 | | | |
| SC-70 | plastic surface-mounted package; 3 leads | SOT323 | | | |
| | Package Name SC-75 SC-59A SC-101 SC-43A | NameDescriptionSC-75plastic surface-mounted package; 3 leadsSC-59Aplastic surface-mounted package; 3 leadsSC-101leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mmSC-43Aplastic single-ended leaded (through hole) package; 3 leads-plastic surface-mounted package; 3 leads | | | |

[1] Also available in SOT54A and SOT54 variant packages (see <u>Section 2</u> and <u>Section 9</u>).

4. Marking

| Table 5. Marking codes | |
|------------------------|-----------------------------|
| Type number | Marking code ^[1] |
| PDTA114TE | 11 |
| PDTA114TK | 23 |
| PDTA114TM | DE |
| PDTA114TS | TA114T |
| PDTA114TT | *11 |
| PDTA114TU | *23 |

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

5. Limiting values

| Table 6. In accordai | Limiting values nce with the Absolute Maximu | um Rating System | (IEC 60 | 134). | | |
|--------------------------------|---|-------------------------------|------------|-------|------|------|
| Symbol | Parameter | Conditions | | Min | Max | Unit |
| V _{CBO} | collector-base voltage | open emitter | | - | -50 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | -50 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | -5 | V |
| lo | output current | | | - | -100 | mA |
| I _{CM} | peak collector current | single pulse; $t_p \leq 1 ms$ | | - | -100 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | | | | |
| | PDTA114TE | | <u>[1]</u> | - | 150 | mW |
| | PDTA114TK | | <u>[1]</u> | - | 250 | mW |
| | PDTA114TM | | [2][3] | - | 250 | mW |
| | PDTA114TS | | <u>[1]</u> | - | 500 | mW |
| | PDTA114TT | | <u>[1]</u> | - | 250 | mW |
| | PDTA114TU | | <u>[1]</u> | - | 200 | mW |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -65 | +150 | °C |
| T _{stg} | storage temperature | | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

6. Thermal characteristics

| Table 7. | Thermal characteristics | | | | | |
|----------------------|---|-------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | | | |
| | PDTA114TE | | <u>[1]</u> _ | - | 833 | K/W |
| | PDTA114TK | | <u>[1]</u> _ | - | 500 | K/W |
| | PDTA114TM | | [2][3] _ | - | 500 | K/W |
| | PDTA114TS | | <u>[1]</u> _ | - | 250 | K/W |
| | PDTA114TT | | <u>[1]</u> _ | - | 500 | K/W |
| | PDTA114TU | | <u>[1]</u> _ | - | 625 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

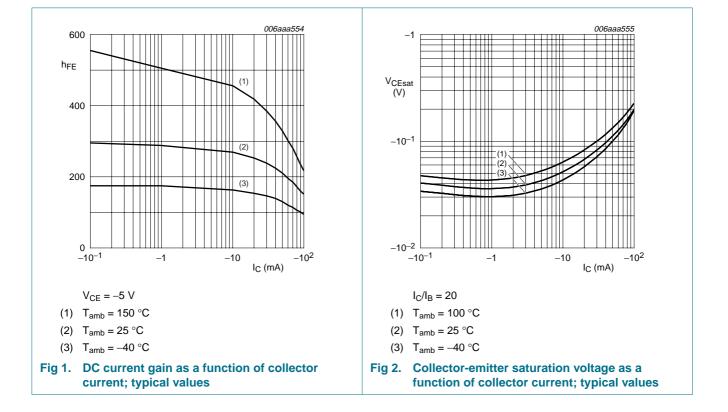
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 60 μ m copper strip line, standard footprint.

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

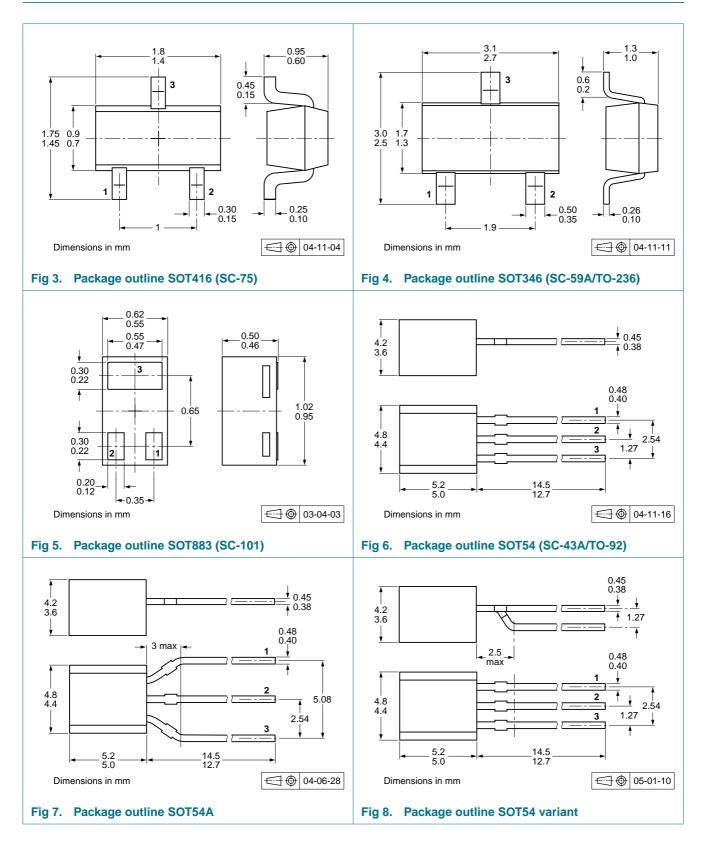
7. Characteristics

| unio | °C unless otherwise sp | | N#! | T | | 11 |
|--------------------|---|---|-----|----------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| I _{CBO} | collector-base cut-off current | $V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$ | - | - | -100 | nA |
| I _{CEO} | collector-emitter | $V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$ | - | - | -1 | μA |
| | cut-off current | $\label{eq:VCE} \begin{array}{l} V_{CE} = -30 \ V; \ I_{B} = 0 \ A; \\ T_{j} = 150 \ ^{\circ}C \end{array}$ | - | - | -50 | μA |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$ | - | - | -100 | nA |
| h _{FE} | DC current gain | V_{CE} = -5 V; I_C = -1 mA | 200 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_{C} = -10 \text{ mA};$ $I_{B} = -0.5 \text{ mA}$ | - | - | -150 | mV |
| R1 | bias resistor 1 (input) | | 7 | 10 | 13 | kΩ |
| C _c | collector capacitance | $V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz | - | - | 3 | pF |



PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

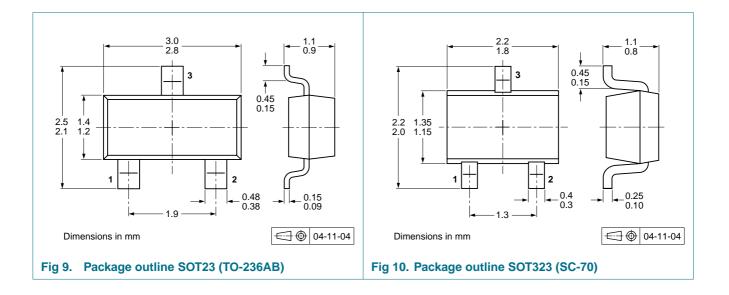
8. Package outline



NXP Semiconductors

PDTA114T series

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open



PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

9. Packing information

| Table 9. Packing methods The indicated -xxx are the last three digits of the 12NC ordering code.[1] | | | | | | |
|---|---------------|--------------------------------|--------|------------------|-------|--|
| Type number | Package | Description | Packir | Packing quantity | | |
| | | | 3000 | 5000 | 10000 | |
| PDTA114TE | SOT416 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |
| PDTA114TK | SOT346 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |
| PDTA114TM | SOT883 | 2 mm pitch, 8 mm tape and reel | - | - | -315 | |
| PDTA114TS | SOT54 | bulk, straight leads | - | -412 | - | |
| | SOT54A | tape and reel, wide pitch | - | - | -116 | |
| | | tape ammopack, wide pitch | - | - | -126 | |
| | SOT54 variant | bulk, delta pinning | - | -112 | - | |
| PDTA114TT | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | - | -235 | |
| PDTA114TU | SOT323 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |

[1] For further information and the availability of packing methods, see <u>Section 12</u>.

PNP resistor-equipped transistors; R1 = 10 kΩ, R2 = open

10. Revision history

| Table 10. Revision hist | tory | | | |
|-------------------------|--|---|--|---|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| PDTA114T_SER_7 | 20070420 | Product data sheet | - | PDTA114T_SERIES_6 |
| Modifications: | guidelines of Legal texts h Type numbe Section 1.2 ^o Section 1.3 ^o Table 4 "Ord Table 5 "Mar Table 6 "Lim Figure 1, 2, Figure 3, 4, Section 9 "P | of this data sheet has been re f NXP Semiconductors. have been adapted to the new r PDTA114TEF removed <u>'Features</u> ": amended <u>'Applications</u> ": amended <u>ering information</u> ": added <u>tking codes</u> ": enhanced table <u>iting values</u> ": I _{CM} peak collect 7 and 8: added 5, 6, 9 and <u>10</u> : superseded by acking information": added Legal information": updated | v company name whe note section tor current conditions | vith the new identity are appropriate. |
| PDTA114T_SERIES_6 | 20040802 | Product specification | - | PDTA114T_SERIES_5 |
| PDTA114T_SERIES_5 | 20030909 | Product specification | - | PDTA114T_SERIES_4 |
| PDTA114T_SERIES_4 | 20030410 | Product specification | - | PDTA114TE_2 PDTA114TK_3 PDTA114TS_2 PDTA114TT_3 PDTA114TU_3 |
| PDTA114TE_2 | 19980723 | Preliminary specification | - | PDTA114TE_1 |
| PDTA114TK_3 | 19980515 | Product specification | - | PDTA114TK_2 |
| PDTA114TS_2 | 19980515 | Product specification | - | PDTA114TS_1 |
| PDTA114TT_3 | 19990413 | Objective specification | - | PDTA114TT_2 |
| PDTA114TU_3 | 19990413 | Product specification | - | PDTA114TU_2 |

11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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